



#### **Features**

- High isolation 5000 VRMS
- DC input with transistor output
- Operating temperature range 55 °C to 110 °C
- External Creepage ≥ 7.5mm (S/SL Type)
- External Creepage ≥ 8.0mm (SLM Type)
- RoHS compliant
- **REACH** compliance
- Green material
- Regulatory Approvals
  - UL UL1577 (E364000)
  - VDE EN60747-5-5(VDE0884-5)
  - CQC GB4943.1, GB8898
  - IEC60065, IEC60950

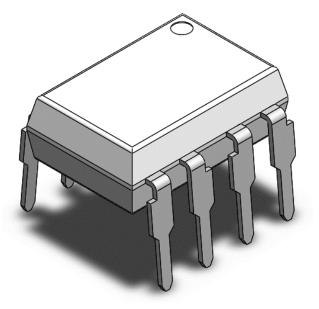
#### **Description**

The CT827 series consists of dual channels each contains a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 8-lead DIP package different lead forming options.

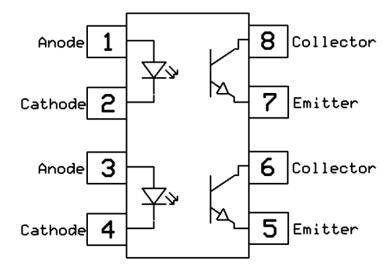
#### **Applications**

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

### **Package Outline**



# **Schematic**



Note: Different lead forming options available. See package dimension.



### CT827 Series

## **DC Input 8-Pin Phototransistor Optocoupler**

### Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage	5000	V <sub>RMS</sub>	
Ртот	Total power dissipation	200	mW	
Topr	Operating temperature	-55 ~ +110	°C	
Тѕтс	Storage temperature	-55 ~ +150	°C	
Tsol	Soldering temperature	260	°C	
Emitter	1 circuit)	·		
l <sub>F</sub>	Forward current	60	mA	
I <sub>F(TRANS)</sub>	Peak transient current (≤1µs P.W,300pps)	1	А	
VR	Reverse voltage	6	V	
P <sub>D</sub>	Emitter power dissipation	100	mW	
Detector	(1 circuit)	·		
PD	Detector power dissipation	150	mW	
Вусео	Collector-Emitter Breakdown Voltage	80	V	
B <sub>VECO</sub>	Emitter-Collector Breakdown Voltage	7	V	
lc	Collector Current	50	mA	



**Electrical Characteristics**  $T_A = 25$ °C (unless otherwise specified)

#### **Emitter Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I <sub>F</sub> =10mA		1.24	1.4	V	
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 6V	-	-	5	μΑ	
C <sub>IN</sub>	Input Capacitance	f= 1MHz	-	10	30	pF	

#### **Detector Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
Bvceo	Collector-Emitter Breakdown	I <sub>C</sub> = 100μA	80	-	-	V	
Bveco	Emitter-Collector Breakdown	I <sub>E</sub> = 100μA	7	-	-	V	
I <sub>CEO</sub>	Collector-Emitter Dark Current	V <sub>CE</sub> = 20V, I <sub>F</sub> =0mA	-	-	100	nA	

#### **Transfer Characteristics**

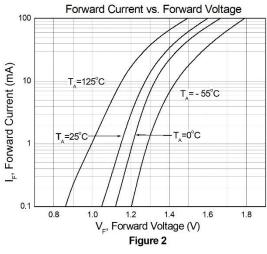
Symbol	Parameters		Test Conditions	Min	Тур	Max	Units	Notes
		CT827	'A IF= 5mA, VcE= 5V	50		600		
CTR		CT827A		80		160	%	
		CT827B		130		260		
	Collector-Emitter Saturation Voltage		I <sub>F</sub> = 20mA, I <sub>C</sub> = 1mA	-	0.1	0.2	V	
VCE(SAT)								
Rio	Isolation Resistance		Vio= 500VDC	5x10 <sup>10</sup>			Ω	
C <sub>IO</sub>	Isolation Capacitance		f= 1MHz		0.5	1	pF	

#### **Switching Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
t <sub>r</sub>	Rise Time	Ic= 2mA, VcE= 2V		6	18	0	
t <sub>f</sub>	Fall Time	R <sub>L</sub> = 100Ω	-	8	18	μS	



#### **Typical Characteristic Curves**



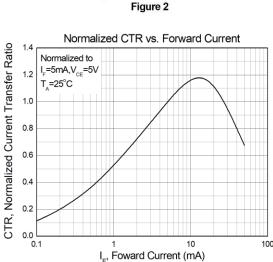
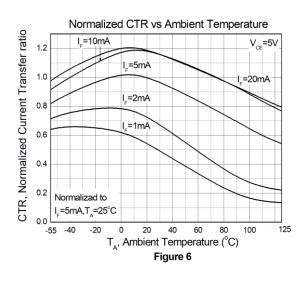
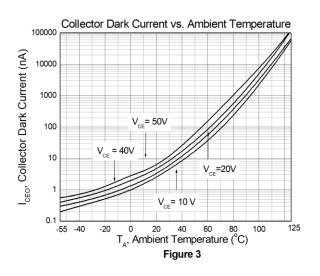
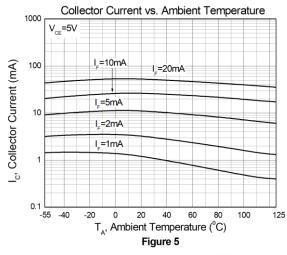
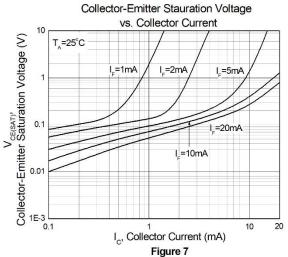


Figure 4





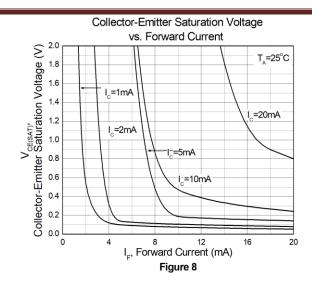


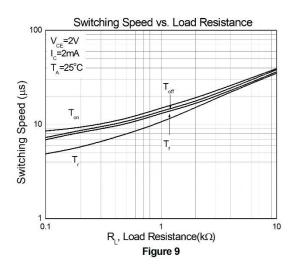


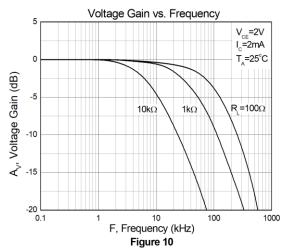


#### CT827 Series

### DC Input 8-Pin Phototransistor Optocoupler

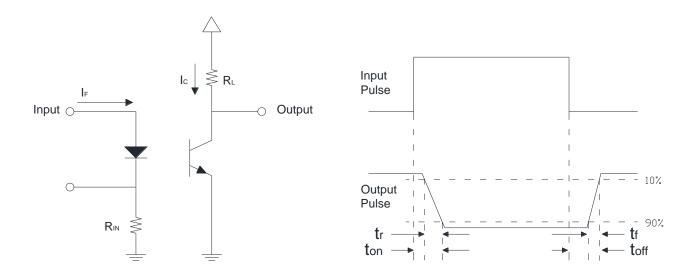








#### **Test Circuit**



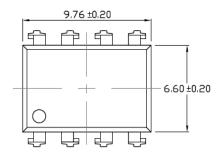
**Figure 12: Switching Time Test Circuits** 

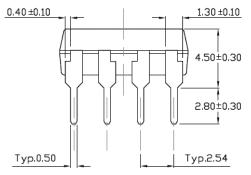


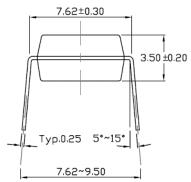


#### Package Dimension Dimensions in mm unless otherwise stated

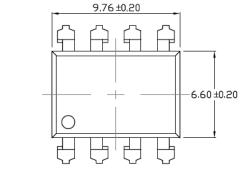
#### Standard DIP - Through Hole

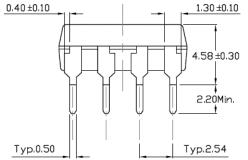


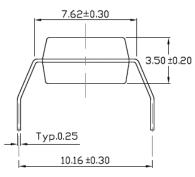




#### **Gullwing (400mil) Lead Forming – Through Hole (M Type)**



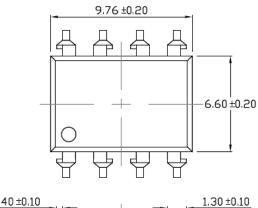


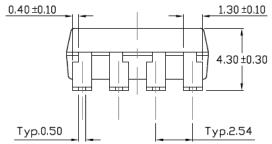


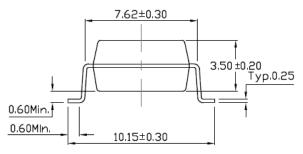




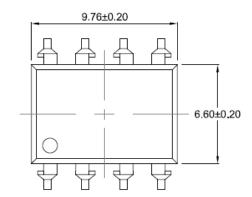
#### **Surface Mount Lead Forming (S Type)**

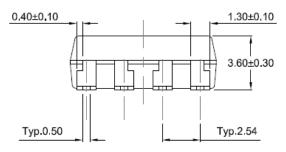


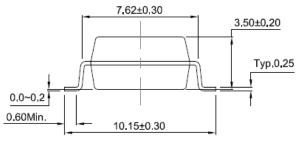




#### **Surface Mount (Low Profile) Lead Forming (SL Type)**



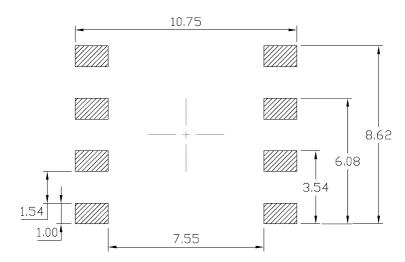




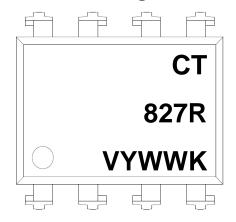




#### Recommended Solder Mask Dimensions in mm unless otherwise stated



#### **Device Marking**



#### Note:

CT : Denotes "CT Micro"

827 : Product Number

R : CTR Rank
V : VDE Option
Y : Fiscal Year
WW : Work Week

K : Production Code





#### **Ordering Information**

### CT827X(V)(Y)(Z)

CT =Denotes "CT Micro"

827 = Product Number

X = Part No. (X=A, B or None)

V = VDE Option ( V or None)

Y = Lead form option (S, SL, M or none)

Z = Tape and reel option (T1, T2 or none)

Option	Description	Quantity
None	ne Standard 8 Pin Dip	
M	M Gullwing (400mil) Lead Forming	
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000 Units/Reel
SL(T1)	SL(T1) Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	
SL(T2)	Surface Mount (Low Profile) Lead Forming- With Option 2 Taping	1000 Units/Reel

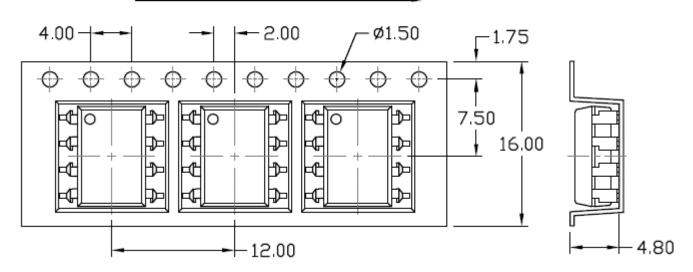




#### Carrier Tape Specifications Dimensions in mm unless otherwise stated

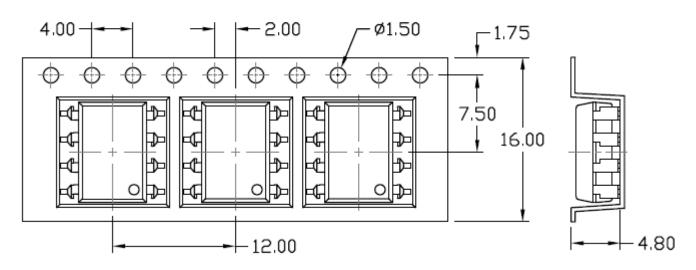
### Option S(T1) & SL(T1)

# Input Direction



#### Option S(T2) & SL(T2)

# Input Direction





#### **Wave soldering (follow the JEDEC standard JESD22-A111)**

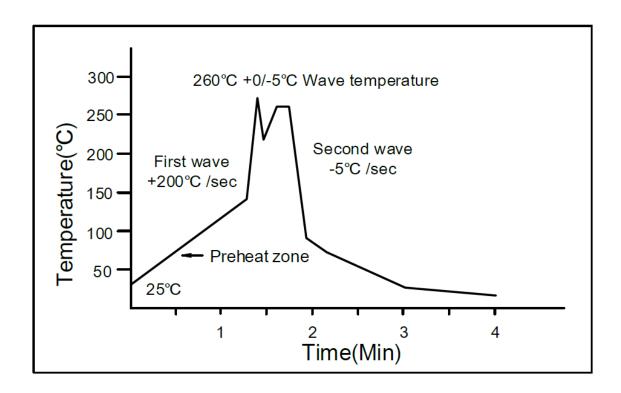
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.



### Hand soldering by soldering iron

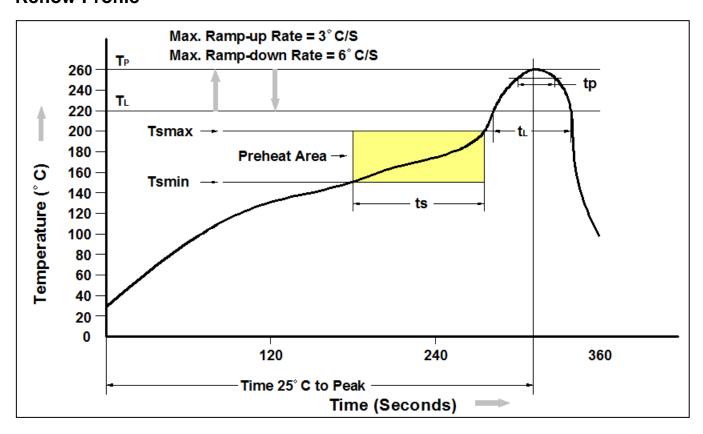
Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: 380+0/-5°C

Time: 3 sec max.



#### **Reflow Profile**



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



#### CT827 Series

### DC Input 8-Pin Phototransistor Optocoupler

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